
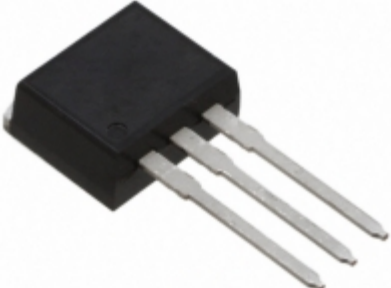
	<h2 style="color: red;">FQI27N25TU</h2>
	<p><b>Hersteller-Teilenummer:</b> <a href="#">FQI27N25TU</a></p> <p><b>Hersteller / Marke:</b> <a href="#">Fairchild/ON Semiconductor</a></p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 250V 25.5A I2PAK</p> <p><b>Datenblätter:</b>  <a href="#">FQI27N25TU.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 1000 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	FQI27N25TU
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 250V 25.5A I2PAK
Kategorie	<a href="#">Diskrete Halbleiterprodukte</a> > <a href="#">Transistoren-FETs</a> ,
Teilstatus	1000 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-262-3 Long Leads, I <sup>2</sup> Pak, TO-262AA
Supplier Device-Gehäuse	I2PAK
Verlustleistung (max)	3.13W (Ta), 180W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	250V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	25.5A (Tc)
Rds On (Max) @ Id, Vgs	110 mOhm @ 12.75A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	65nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	2450pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tube



















































FQI27N25TU ist neu im Original, Suche FQI27N25TU Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQI27N25TU Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQI27N25TU: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>FQI1P50TU</b> Fairchild/ON Semiconductor MOSFET P-CH 500V 1.5A I2PAK</p>	 <p><b>FQI27P06</b> FAIRCHILD FQI27P06 FAIRCHILD</p>	 <p><b>FQI19N20TU</b> Fairchild/ON Semiconductor MOSFET N-CH 200V 19.4A I2PAK</p>	 <p><b>FQI1P50TU</b> AMI Semiconductor / ON Semiconductor MOSFET P-CH 500V 1.5A I2PAK</p>
 <p><b>FQI19N20TU</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 19.4A I2PAK</p>	 <p><b>FQI27P06TU</b> AMI Semiconductor / ON Semiconductor MOSFET P-CH 60V 27A I2PAK</p>	 <p><b>FQI27P06TU</b> Fairchild/ON Semiconductor MOSFET P-CH 60V 27A I2PAK</p>	 <p><b>FQI27N25TU</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 250V 25.5A I2PAK</p>

### heiße Teile

Mehr

 FQI10N20CTU	 FQI10N20CTU	 FQI10N20LTU	 FQI11P06TU	 FQI11P06TU
 FQI12N60C	 FQI13N06	 FQI13N06L	 FQI13N50	 FQI13N50C
 FQI13N50CTU	 FQI13N50CTU	 FQI16N15TU	 FQI17N08L	 FQI17P06TU
 FQI17P06TU	 FQI17P20	 FQI19N10LTU	 FQI19N20TU	 FQI19N20TU
 FQI27N25TU	 FQI2N50TU	 FQI2NA90	 FQI2P25TU	 FQI2P25TU
 FQI3N25TU	 FQI3N25TU	 FQI3N30TU	 FQI3N30TU	 FQI47P06TU
 FQI47P06TU	 FQI4N20TU	 FQI4N20TU	 FQI4N80TU	 FQI4N80TU
 FQI4N90TU	 FQI4N90TU	 FQI50N06	 FQI50N06L	 FQI5N20L
 FQI5N50CTU	 FQI5N50CTU	 FQI5N50TU	 FQI5N60C	 FQI5N60CTU
 FQI5N60CTU	 FQI5N60TU	 FQI6N25TU	 FQI6N40TU	 FQI6N60C

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

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